

PNP - 2N6107, 2N6109, 2N6111; NPN - 2N6288, 2N6292

Complementary Silicon Plastic Power Transistors

These devices are designed for use in general-purpose amplifier and switching applications.

Features

- DC Current Gain Specified to 7.0 Amperes
 - $h_{FE} = 30\text{--}150 @ I_C$
 - = 3.0 Adc – 2N6111, 2N6288
 - = 2.3 (Min) @ $I_C = 7.0 \text{ Adc}$ – All Devices
- Collector-Emitter Sustaining Voltage –
 - $V_{CEO(\text{sus})} = 30 \text{ Vdc (Min)} - 2N6111, 2N6288$
 - = 50 Vdc (Min) – 2N6109
 - = 70 Vdc (Min) – 2N6107, 2N6292
- High Current Gain – Bandwidth Product
 - $f_T = 4.0 \text{ MHz (Min)} @ I_C = 500 \text{ mA}dc - 2N6288, 90, 92$
 - = 10 MHz (Min) @ $I_C = 500 \text{ mA}dc - 2N6107, 09, 11$
- TO-220AB Compact Package
- Pb-Free Packages are Available*

MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}		Vdc
2N6111, 2N6288		30	
2N6109		50	
2N6107, 2N6292		70	
Collector-Base Voltage	V_{CB}		Vdc
2N6111, 2N6288		40	
2N6109		60	
2N6107, 2N6292		80	
Emitter-Base Voltage	V_{EB}	5.0	Vdc
Collector Current – Continuous	I_C	7.0	Adc
– Peak		10	
Base Current	I_B	3.0	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$	P_D	40	W
Derate above 25°C		0.32	$\text{W}/^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	3.125	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Indicates JEDEC Registered Data.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERMM/D.

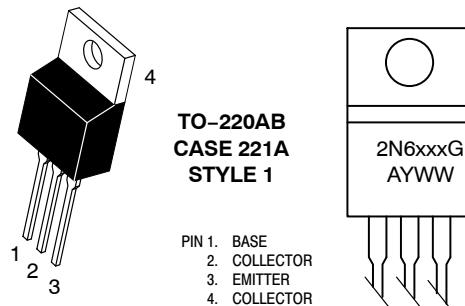


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7 AMPERE POWER TRANSISTORS COMPLEMENTARY SILICON 30 – 50 – 70 VOLTS, 40 WATTS

MARKING DIAGRAM



2N6xxx = Specific Device Code

xxx = See Table on Page 4

G = Pb-Free Package

A = Assembly Location

Y = Year

WW = Work Week

ORDERING INFORMATION

See detailed ordering, marking, and shipping information in the package dimensions section on page 4 of this data sheet.

PNP – 2N6107, 2N6109, 2N6111; NPN – 2N6288, 2N6292

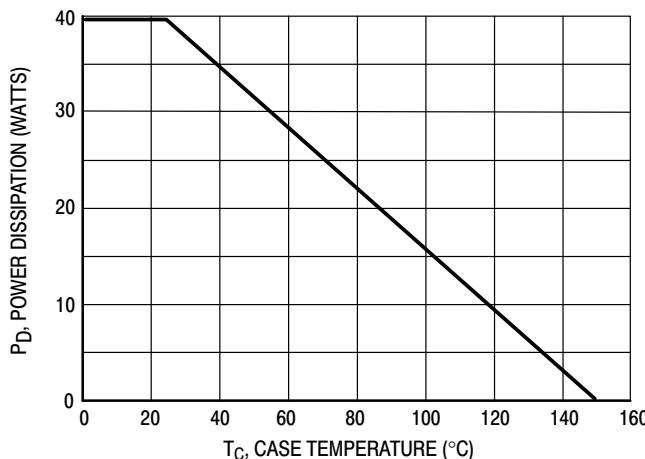


Figure 1. Power Derating

ELECTRICAL CHARACTERISTICS ($T_c = 25^\circ\text{C}$ unless otherwise noted) (Note 2)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Sustaining Voltage (Note 3) ($I_C = 100 \text{ mA}_\text{dc}$, $I_B = 0$)	$V_{CEO(\text{sus})}$	30 50 70	—	V_dc
2N6111, 2N6288 2N6109 2N6107, 2N6292				
Collector Cutoff Current ($V_{CE} = 20 \text{ V}_\text{dc}$, $I_B = 0$) ($V_{CE} = 40 \text{ V}_\text{dc}$, $I_B = 0$) ($V_{CE} = 60 \text{ V}_\text{dc}$, $I_B = 0$)	I_{CEO}	— — —	1.0 1.0 1.0	mA_dc
2N6111, 2N6288 2N6109 2N6107, 2N6292				
Collector Cutoff Current ($V_{CE} = 40 \text{ V}_\text{dc}$, $V_{EB(\text{off})} = 1.5 \text{ V}_\text{dc}$) ($V_{CE} = 60 \text{ V}_\text{dc}$, $V_{EB(\text{off})} = 1.5 \text{ V}_\text{dc}$) ($V_{CE} = 80 \text{ V}_\text{dc}$, $V_{EB(\text{off})} = 1.5 \text{ V}_\text{dc}$) ($V_{CE} = 30 \text{ V}_\text{dc}$, $V_{EB(\text{off})} = 1.5 \text{ V}_\text{dc}$, $T_c = 150^\circ\text{C}$) ($V_{CE} = 50 \text{ V}_\text{dc}$, $V_{EB(\text{off})} = 1.5 \text{ V}_\text{dc}$, $T_c = 150^\circ\text{C}$) ($V_{CE} = 70 \text{ V}_\text{dc}$, $V_{EB(\text{off})} = 1.5 \text{ V}_\text{dc}$, $T_c = 150^\circ\text{C}$)	I_{CEX}	— — — — — —	100 100 100 2.0 2.0 2.0	μA_dc
2N6111, 2N6288 2N6109 2N6107, 2N6292 2N6111, 2N6288 2N6109 2N6107, 2N6292				
Emitter Cutoff Current ($V_{BE} = 5.0 \text{ V}_\text{dc}$, $I_C = 0$)	I_{EBO}	—	1.0	mA_dc

ON CHARACTERISTICS (Note 3)

DC Current Gain ($I_C = 2.0 \text{ Adc}$, $V_{CE} = 4.0 \text{ V}_\text{dc}$) ($I_C = 2.5 \text{ Adc}$, $V_{CE} = 4.0 \text{ V}_\text{dc}$) ($I_C = 3.0 \text{ Adc}$, $V_{CE} = 4.0 \text{ V}_\text{dc}$) ($I_C = 7.0 \text{ Adc}$, $V_{CE} = 4.0 \text{ V}_\text{dc}$)	h_{FE}	30 30 30 2.3	150 150 150 —	—
2N6107, 2N6292 2N6109 2N6111, 2N6288 All Devices				
Collector-Emitter Saturation Voltage ($I_C = 7.0 \text{ Adc}$, $I_B = 3.0 \text{ Adc}$)	$V_{CE(\text{sat})}$	—	3.5	V_dc
Base-Emitter On Voltage ($I_C = 7.0 \text{ Adc}$, $V_{CE} = 4.0 \text{ V}_\text{dc}$)	$V_{BE(\text{on})}$	—	3.0	V_dc

DYNAMIC CHARACTERISTICS

Current Gain — Bandwidth Product (Note 4) ($I_C = 500 \text{ mA}_\text{dc}$, $V_{CE} = 4.0 \text{ V}_\text{dc}$, $f_{\text{test}} = 1.0 \text{ MHz}$)	f_T	4.0 10	— —	MHz
2N6288, 92 2N6107, 09, 11				
Output Capacitance ($V_{CB} = 10 \text{ V}_\text{dc}$, $I_E = 0$, $f = 1.0 \text{ MHz}$)	C_{ob}	—	250	pF
Small-Signal Current Gain ($I_C = 0.5 \text{ Adc}$, $V_{CE} = 4.0 \text{ V}_\text{dc}$, $f = 50 \text{ kHz}$)	h_{fe}	20	—	—

- 2. Indicates JEDEC Registered Data.
- 3. Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.
- 4. $f_T = |h_{fe}| \cdot f_{\text{test}}$

PNP – 2N6107, 2N6109, 2N6111; NPN – 2N6288, 2N6292

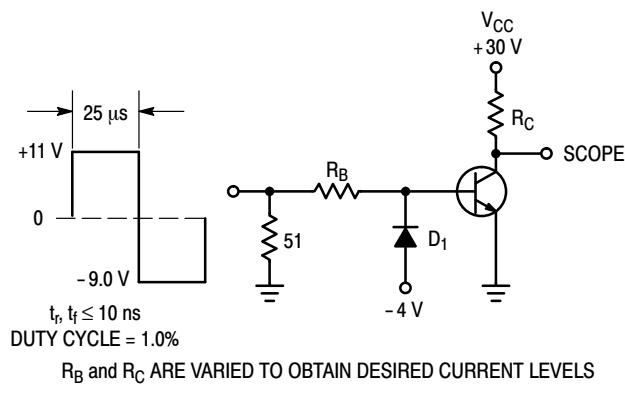


Figure 2. Switching Time Test Circuit

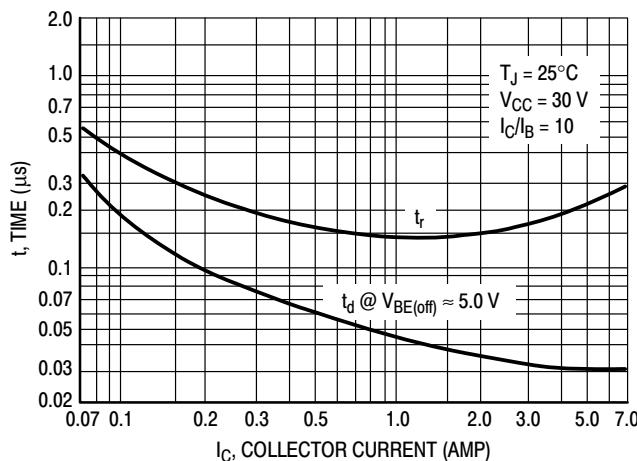


Figure 3. Turn-On Time

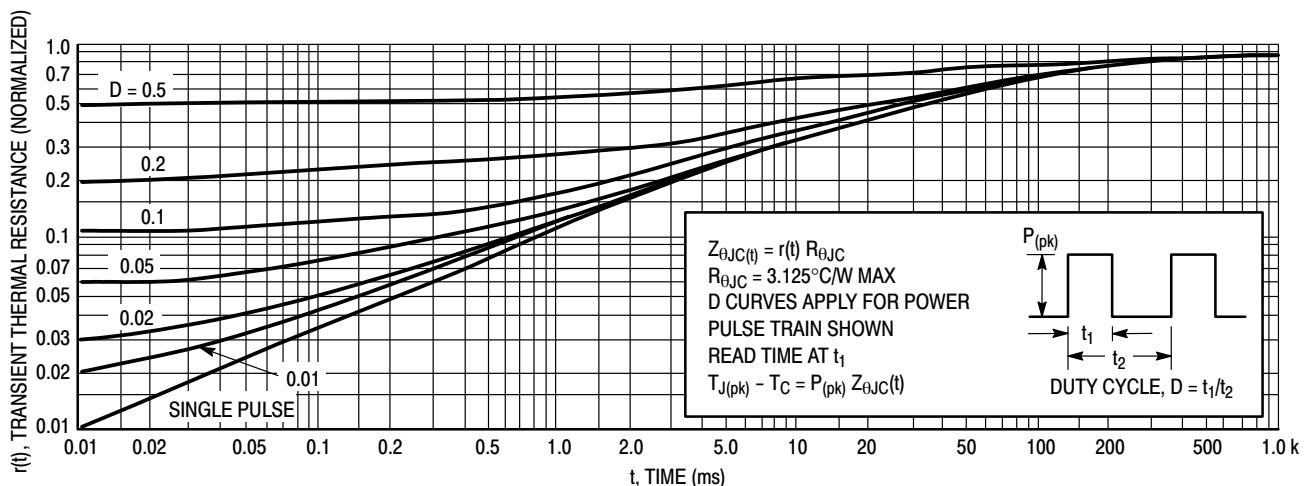


Figure 4. Thermal Response

PNP – 2N6107, 2N6109, 2N6111; NPN – 2N6288, 2N6292

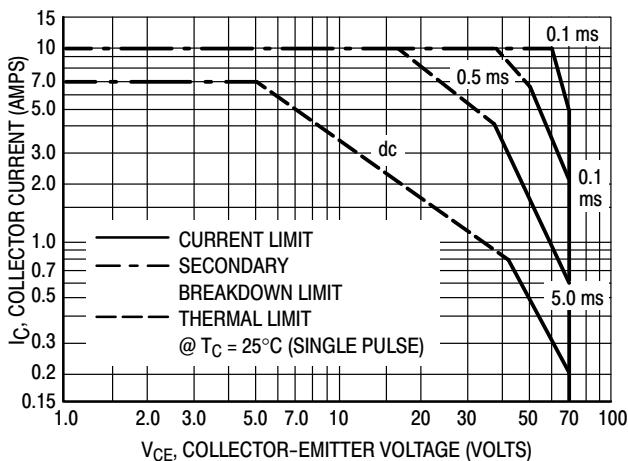


Figure 5. Active-Region Safe Operating Area

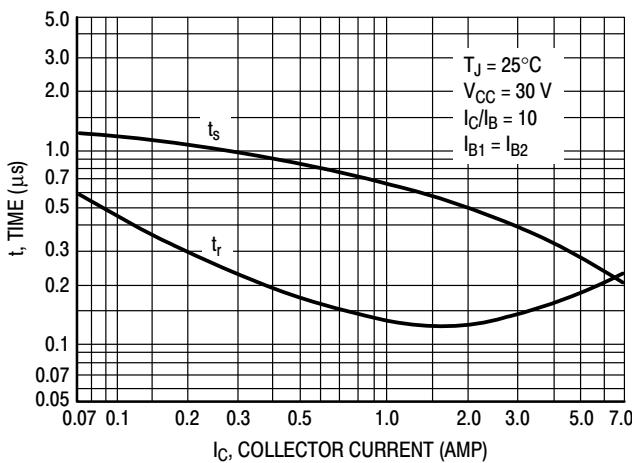


Figure 6. Turn-Off Time

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 150^\circ\text{C}$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^\circ\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

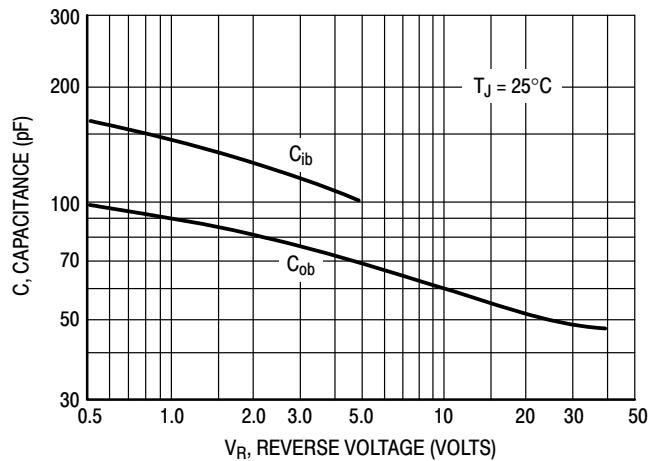


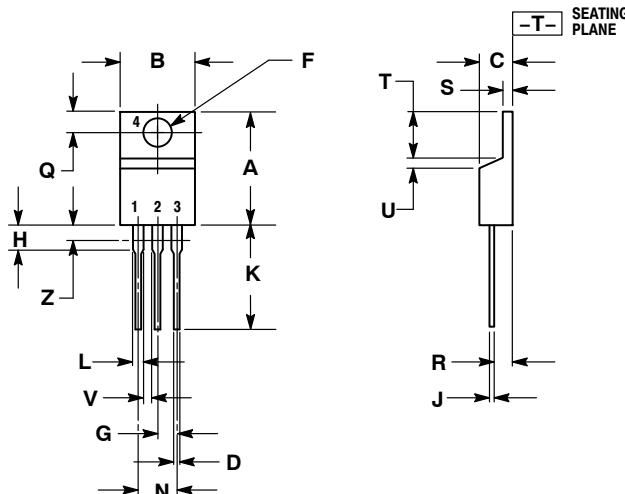
Figure 7. Capacitance

ORDERING INFORMATION

Device	Device Marking	Package	Shipping
2N6107	2N6107	TO-220AB	50 Units / Rail
2N6107G		TO-220AB (Pb-Free)	
2N6109	2N6109	TO-220AB	50 Units / Rail
2N6109G		TO-220AB (Pb-Free)	
2N6111	2N6111	TO-220AB	50 Units / Rail
2N6111G		TO-220AB (Pb-Free)	
2N6288	2N6288	TO-220AB	50 Units / Rail
2N6288G		TO-220AB (Pb-Free)	
2N6292	2N6292	TO-220AB	50 Units / Rail
2N6292G		TO-220AB (Pb-Free)	

PACKAGE DIMENSIONS

**TO-220
CASE 221A-09
ISSUE AG**



NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.036	0.64	0.91
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
H	0.110	0.161	2.80	4.10
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

STYLE 1:
 PIN 1. BASE
 2. COLLECTOR
 3. Emitter
 4. COLLECTOR

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